N-Channel Silicon MOSFET



2SK1446LS

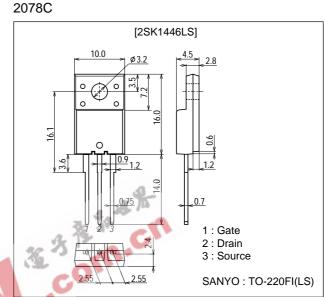
# **Ultrahigh-Speed Switching Applications**

## Features

- · Low ON-resistance.
- Ultrahigh-speed switching.
- · Micaless package facilitating mounting.

# **Package Dimensions**

unit : mm



# **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol		Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS			450	V
Gate-to-Source Voltage	VGSS			±30	V
Drain Current (DC)	ID			7	А
Drain Current (Pulse)	IDP	PW≤10μ	s, duty cycle≤1%	28	А
Allowable Power Dissipation	PD			2.0	W
		Tc=25°C		35	W
Channel Temperature	Tch			150	°C
Storage Temperature	Tstg			-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Symbol	Conditions	Ratings			Unit
	Conditions	min	typ	max	Unit
V(BR)DSS	ID=1mA, VGS=0	450			V
IDSS	VDS=450V, VGS=0			1.0	mA
IGSS	V <sub>GS</sub> =±30V, V <sub>DS</sub> =0			±100	nA
	V <sub>(BR)DSS</sub>	V(BR)DSS ID=1mA, VGS=0   IDSS VDS=450V, VGS=0	V(BR)DSS ID=1mA, VGS=0 450   IDSS VDS=450V, VGS=0 450	Symbol Conditions min typ   V(BR)DSS ID=1mA, VGS=0 450 450   IDSS VDS=450V, VGS=0 450 450	Symbol Conditions min typ max   V(BR)DSS ID=1mA, VGS=0 450 1000000000000000000000000000000000000

(Note) Be careful in handling the 2SK1446LS because it has no protection diode between gate and source.

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Marking: K1446

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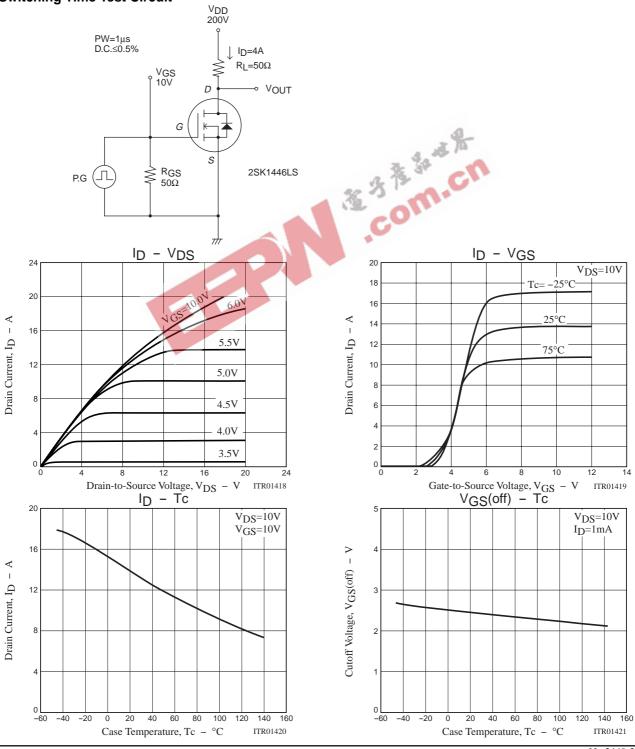
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#### N1501 TS IM TA-3431 / 61099 TH (KT) / 72597 TS (KOTO) / 7151 JN (KOTO) No.3449-1/4

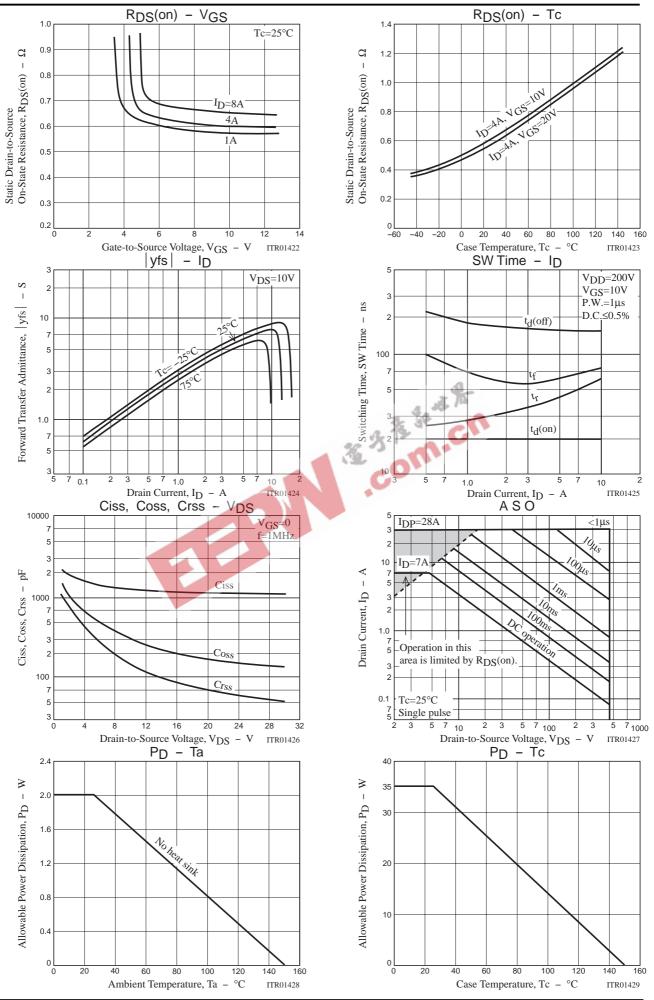
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Parameter	Symbol	Conditions	Ratings			Unit
Falameter		Conditions	min	typ	max	Unit
Cutoff Voltage	V <sub>GS</sub> (off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	2.0		3.0	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =4A	3.0	6.0		S
Static Drain-to-Source On-State Resistance	RDS(on)	ID=4A, VGS=10V		0.6	0.8	Ω
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz		1200		pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		180		pF
Reverse Transfer Capacitance	Crss	VDS=20V, f=1MHz		70		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	ID=4A, VGS=10V, VDD=200V, RGS=50Ω		20		ns
Rise Time	tr	ID=4A, VGS=10V, VDD=200V, RGS=50Ω		40		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	ID=4A, VGS=10V, VDD=200V, RGS=50Ω		160		ns
Fall Time	tf	ID=4A, VGS=10V, VDD=200V, RGS=50Ω		60		ns
Diode Forward Voltage	V <sub>SD</sub>	IS=7A, VGS=0			1.8	V

#### Switching Time Test Circuit



No.3449-2/4



No.3449-3/4

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